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View Online at https://aerobasegroup.com/nsn/5961-01-147-2392 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **End Application:** An/alr-20a **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and quality assurance level tx and reverse polarity **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 reverse voltage, instantaneous and 800.0 working peak reverse voltage, peak total value **Current Rating Per Characteristic:** 35.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-s-19500/297 government specification Shelf Life:

Demilitarization: Yes - demil/mli

Unit Of Measure:

N/a

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